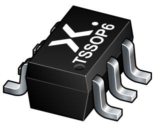


NHUMB10/13/9 series

80 V, 100 mA PNP/PNP resistor-equipped double transistors

Rev. 1 — 23 July 2020 Product data sheet

1. General description

PNP/PNP Resistor-Equipped double Transistor (RET) family in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	R1	R2	Package		NPN/NPN complement:	NPN/PNP complement:
	kΩ	kΩ	Nexperia	JEITA		
NHUMB10	2.2	47	SOT363	SC-88	NHUMH10	NHUMD10
NHUMB13	4.7	47			NHUMH13	NHUMD13
NHUMB9	10	47			NHUMH9	NHUMD9

2. Features and benefits

- 100 mA output current capability
- High breakdown voltage
- Built-in resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

3. Applications

- Digital applications
- Cost saving alternative for BC856 series in digital applications
- Controlling IC inputs
- Switching loads

4. Quick reference data

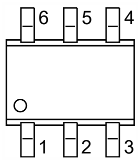
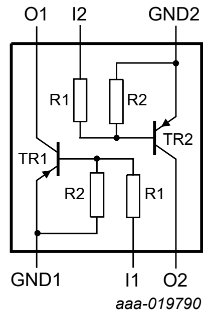
Table 2. Quick reference data

T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Per transistor						
V_{CEO}	collector-emitter voltage	open base	-	-	-80	V
I_O	output current		-	-	-100	mA

5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		
2	I1	input (base) TR1		
3	O2	output (collector) TR2		
4	GND2	GND (emitter) TR2		
5	I2	input (base) TR2		
6	O1	output (collector) TR1		

6. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
NHUMB10	SC-88	plastic surface-mounted package; 6 leads	SOT363
NHUMB13			
NHUMB9			

7. Marking

Table 5. Marking

Type number	Marking code [1]
NHUMB10	6B%
NHUMB13	6D%
NHUMB9	6A%

[1] % = placeholder for manufacturing site code

8. Limiting values

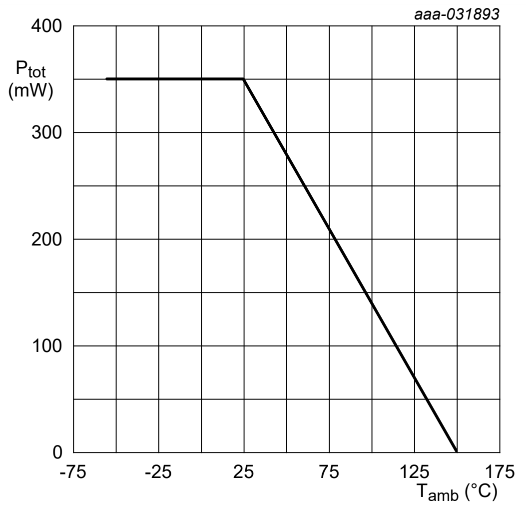
Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Max	Unit
Per transistor					
V_{CBO}	collector-base voltage	open emitter	-	-80	V
V_{CEO}	collector-emitter voltage	open base	-	-80	V
V_{EBO}	emitter-base voltage	open collector	-	-7	V
V_I	input voltage				
	NHUMB10		-20	+7	V
	NHUMB13		-30	+7	V
	NHUMB9		-40	+7	V
I_O	output current		-	-100	mA
P_{tot}	total power dissipation	T_{amb} ≤ 25 °C [1]	-	235	mW
Per device					
P_{tot}	total power dissipation	T_{amb} ≤ 25 °C [1]	-	350	mW
T_j	junction temperature		-	150	°C
T_{amb}	ambient temperature		-55	150	°C
T_{stg}	storage temperature		-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.



FR4 PCB, single-sided copper, standard footprint

Fig. 1. Per device: Power derating curve SOT363 (SC-88)

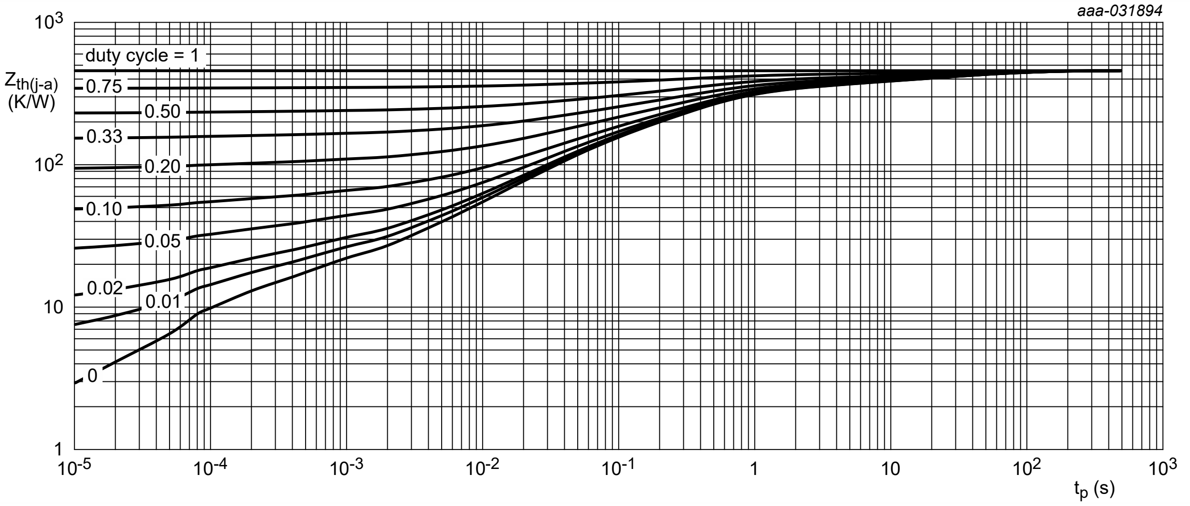
9. Thermal characteristics

Table 7. Thermal characteristics

T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	532	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	-	150	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	358	K/W

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.



FR4 PCB, single-sided copper, tin-plated and standard footprint

Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

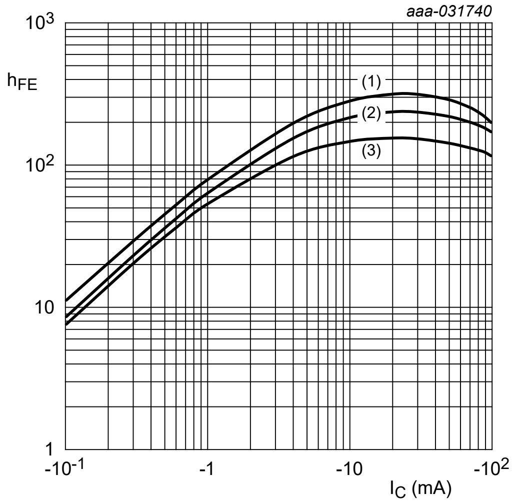
10. Characteristics

Table 8. Characteristics

T_{amb} = 25 °C unless otherwise specified.

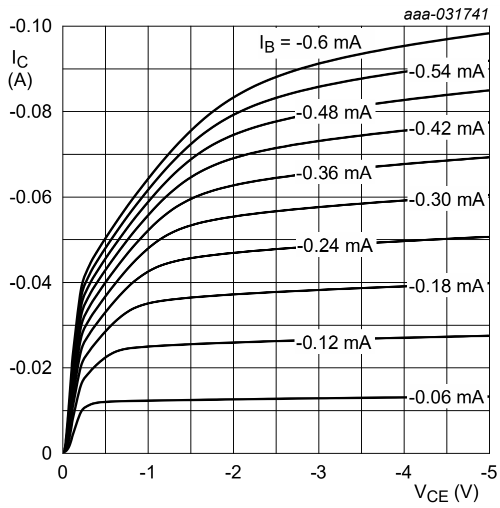
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Per transistor							
$V_{(BR)CBO}$	collector-base breakdown voltage	I_C = -100 µA; I_E = 0 A		-80	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	I_C = -2 mA; I_B = 0 A		-80	-	-	V
I_{CBO}	collector-base cut-off current	V_{CB} = -80 V; I_E = 0 A		-	-	-100	nA
I_{CEO}	collector-emitter cut-off current	V_{CE} = -60 V; I_B = 0 A		-	-	-100	nA
		V_{CE} = -60 V; I_B = 0 A; T_j = 150 °C		-	-	-5	µA
I_{EBO}	emitter-base cut-off current						
	NHUMB10	V_{EB} = -7 V; I_C = 0 A		-	-	-270	µA
	NHUMB13			-	-	-260	µA
	NHUMB9			-	-	-230	µA
h_{FE}	DC current gain	V_{CE} = -5 V; I_C = -10 mA		100	-	-	
V_{CEsat}	collector-emitter saturation voltage	I_C = -10 mA; I_B = -0.5 mA		-	-	-100	mV
$V_{I(off)}$	off-state input voltage						
	NHUMB10	V_{CE} = -5 V ; I_C = -100 µA		-	-595	-500	mV
	NHUMB13				-625	-500	mV
	NHUMB9				-690	-500	mV
$V_{I(on)}$	on-state input voltage						
	NHUMB10	V_{CE} = -0.3 V ; I_C = -10 mA		-1.2	-0.81	-	V
	NHUMB13			-1.4	-0.95	-	V
	NHUMB9			-1.6	-1.22	-	V
R1	bias resistor 1 (input)		[1]				
	NHUMB10			1.54	2.2	2.86	kΩ
	NHUMB13			3.3	4.7	6.1	kΩ
	NHUMB9			7	10	13	kΩ
R2/R1	bias resistor ratio		[1]				
	NHUMB10			17	21	26	
	NHUMB13			8	10	12	
	NHUMB9			3.7	4.7	5.7	
f_T	transition frequency	V_{CE} = -5 V; I_C = -10 mA; f = 100 MHz	[2]	-	150	-	MHz
C_c	collector capacitance	V_{CB} = -10 V; I_E = i_e = 0 A; f = 1 MHz		-	-	3	pF

[1] See section "Test information" for resistor calculation and test conditions
[2] Characteristics of built-in transistor



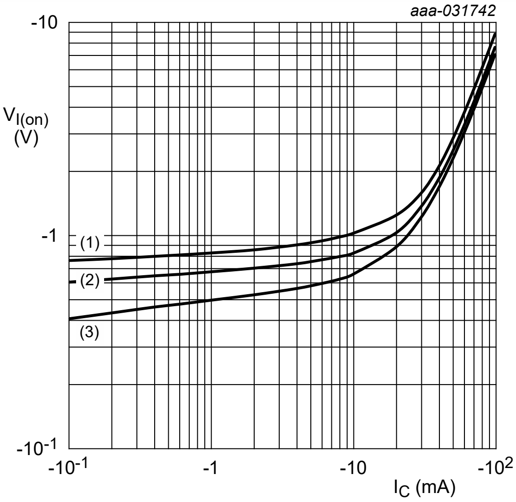
V_{CE} = -5 V
(1) T_{amb} = 100 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = -40 °C

Fig. 3. NHUMB10: DC current gain as a function of collector current; typical values



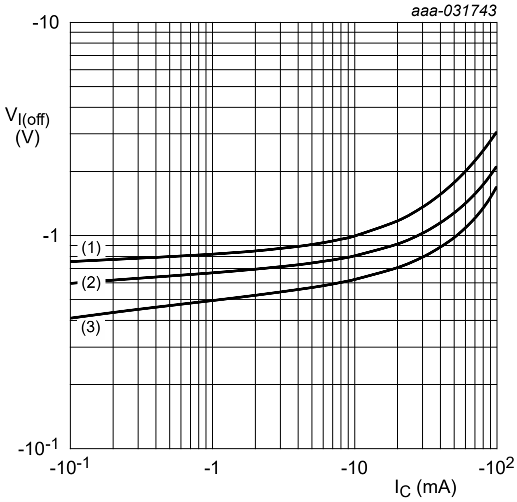
T_{amb} = 25 °C

Fig. 4. NHUMB10: Collector current as a function of collector-emitter voltage; typical values



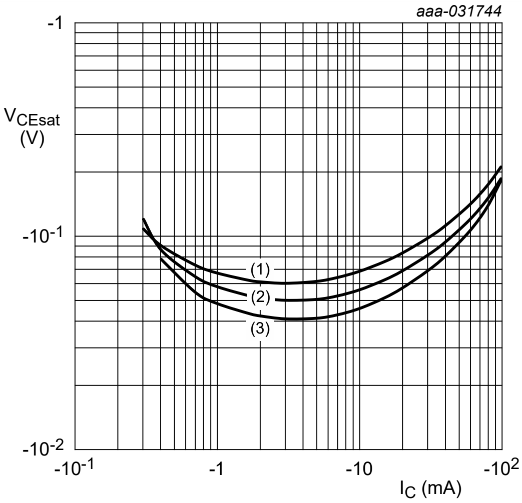
V_{CE} = -0.3 V
(1) T_{amb} = -40 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 100 °C

Fig. 5. NHUMB10: On-state input voltage as a function of collector current; typical values



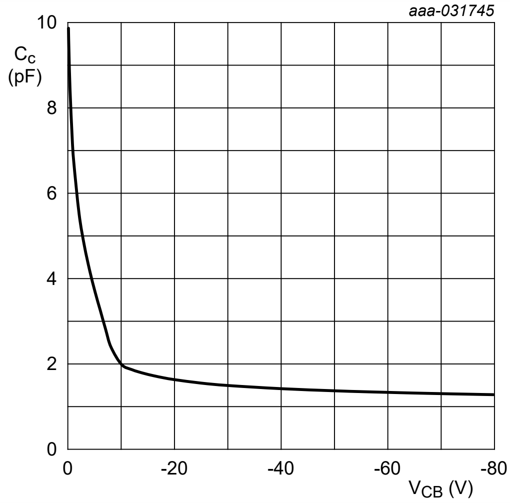
V_{CE} = -5 V
(1) T_{amb} = -40 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 100 °C

Fig. 6. NHUMB10: Off-state input voltage as a function of collector current; typical values



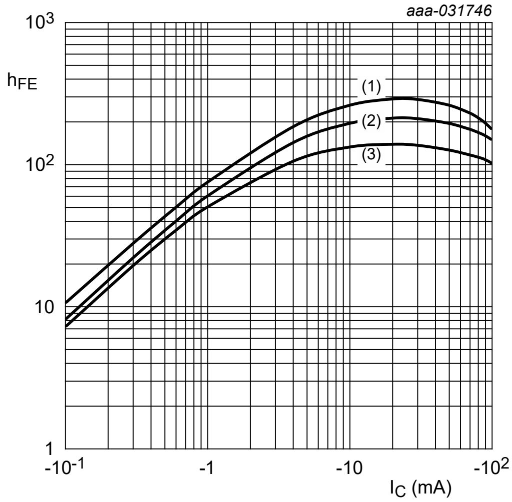
$I_C/I_B = 20$
(1) T_{amb} = 100 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = -40 °C

Fig. 7. NHUMB10: Collector-emitter saturation voltage as a function of collector current; typical values



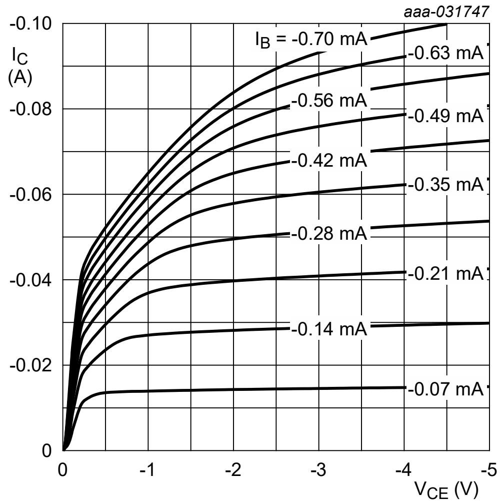
f = 1 MHz
T_{amb} = 25 °C

Fig. 8. NHUMB10: Collector capacitance as a function of collector-base voltage; typical values



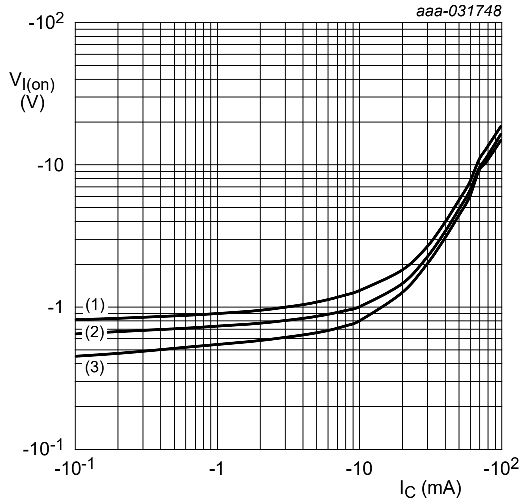
V_{CE} = -5 V
(1) T_{amb} = 100 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = -40 °C

Fig. 9. NHUMB13: DC current gain as a function of collector current; typical values



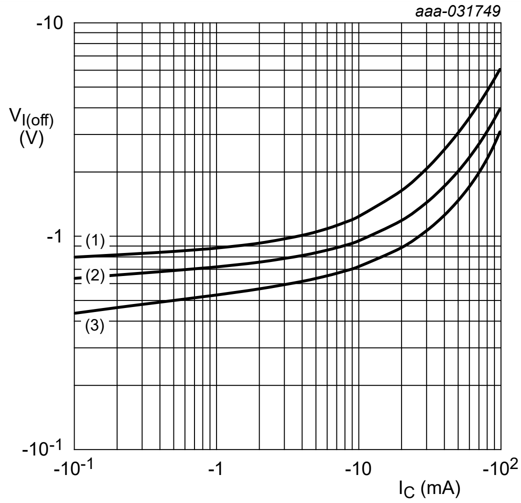
T_{amb} = 25 °C

Fig. 10. NHUMB13: Collector current as a function of collector-emitter voltage; typical values



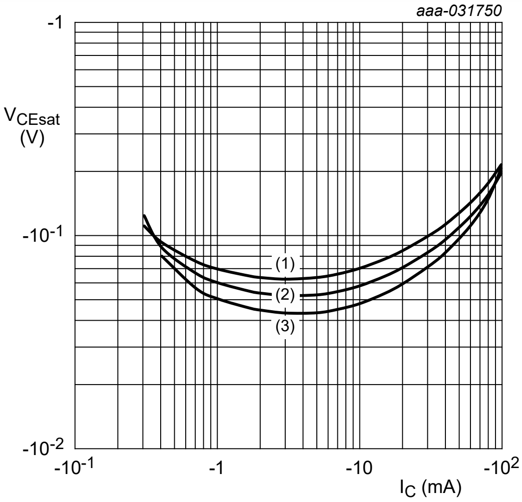
V_{CE} = -0.3 V
(1) T_{amb} = -40 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 100 °C

Fig. 11. NHUMB13: On-state input voltage as a function of collector current; typical values



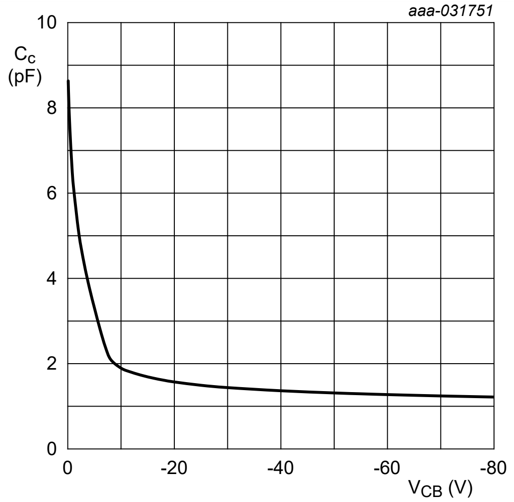
V_{CE} = -5 V
(1) T_{amb} = -40 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = 100 °C

Fig. 12. NHUMB13: Off-state input voltage as a function of collector current; typical values



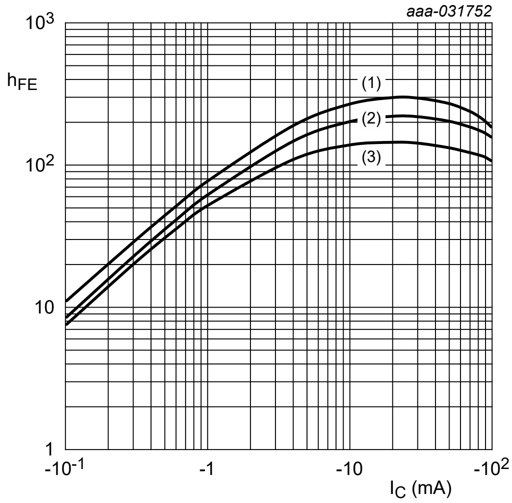
I_C/I_B = 20
(1) T_{amb} = 100 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = -40 °C

Fig. 13. NHUMB13: Collector-emitter saturation voltage as a function of collector current; typical values



f = 1 MHz
T_{amb} = 25 °C

Fig. 14. NHUMB13: Collector capacitance as a function of collector-base voltage; typical values



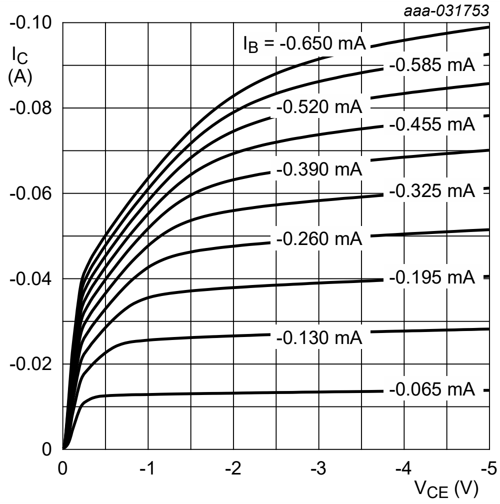
V_{CE} = -5 V

(1) T_{amb} = 100 °C

(2) T_{amb} = 25 °C

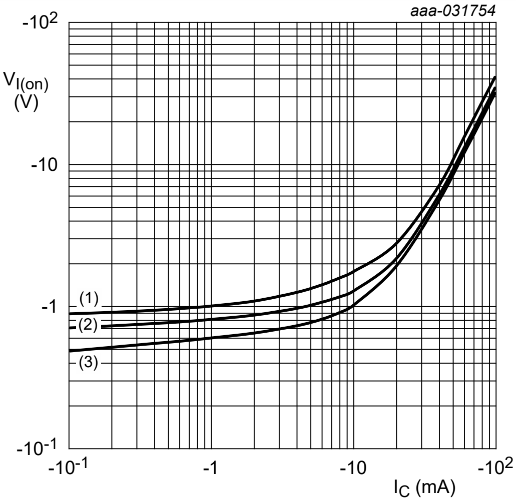
(3) T_{amb} = -40 °C

Fig. 15. NHUMB9: DC current gain as a function of collector current; typical values



T_{amb} = 25 °C

Fig. 16. NHUMB9: Collector current as a function of collector-emitter voltage; typical values



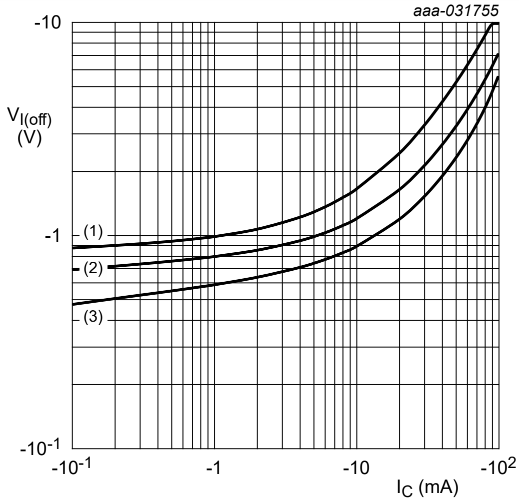
V_{CE} = -0.3 V

(1) T_{amb} = -40 °C

(2) T_{amb} = 25 °C

(3) T_{amb} = 100 °C

Fig. 17. NHUMB9: On-state input voltage as a function of collector current; typical values



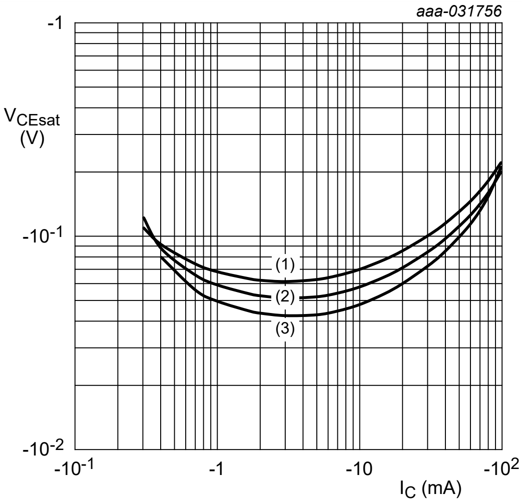
V_{CE} = -5 V

(1) T_{amb} = -40 °C

(2) T_{amb} = 25 °C

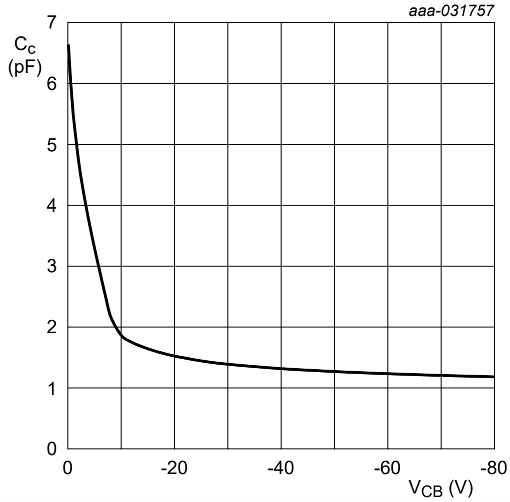
(3) T_{amb} = 100 °C

Fig. 18. NHUMB9: Off-state input voltage as a function of collector current; typical values



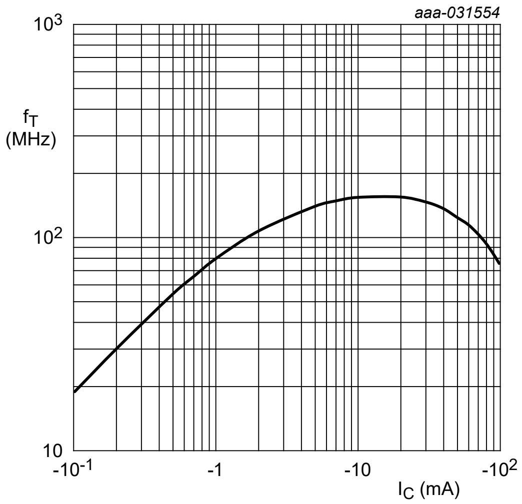
$I_C/I_B = 20$
(1) T_{amb} = 100 °C
(2) T_{amb} = 25 °C
(3) T_{amb} = -40 °C

Fig. 19. NHUMB9: Collector-emitter saturation voltage as a function of collector current; typical values



f = 1 MHz
T_{amb} = 25 °C

Fig. 20. NHUMB9: Collector capacitance as a function of collector-base voltage; typical values



f = 100 MHz
V_{CE} = -5 V
T_{amb} = 25 °C

Fig. 21. Transition frequency as a function of collector current; typical values of built-in transistor

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

Resistor calculation

- Calculation of bias resistor 1 (R1)

$$R_1 = \frac{V(I_{I2}) - V(I_{I1})}{I_{I2} - I_{I1}}$$

- Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I_{I4}) - V(I_{I3})}{R1 \cdot (I_{I4} - I_{I3})} - 1$$

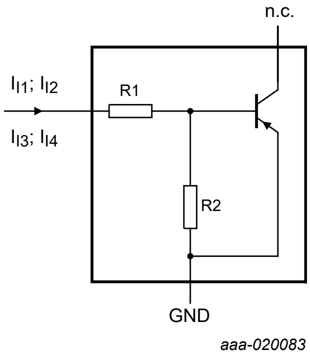


Fig. 22. PNP transistor: Resistor test circuit

Resistor test conditions

Table 9. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I_{I1}	I_{I2}	I_{I3}	I_{I4}
Per transistor						
NHUMB10	2.2	47	-1.6 mA	-2.4 mA	55 µA	105 µA
NHUMB13	4.7	47	-1.2 mA	-1.8 mA	55 µA	105 µA
NHUMB9	10	47	-0.8 mA	-1.1 mA	55 µA	105 µA

12. Package outline

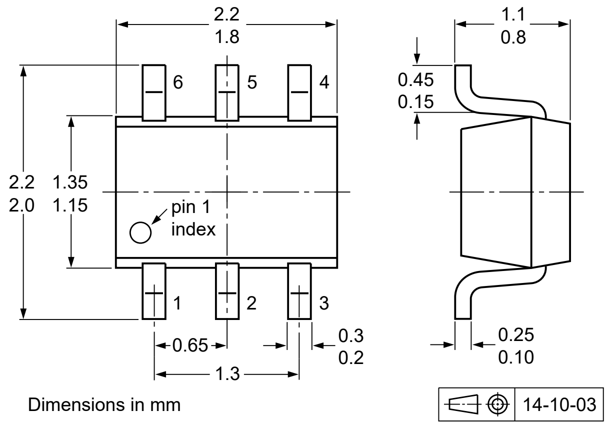


Fig. 23. Package outline SOT363 (SC-88)

13. Soldering

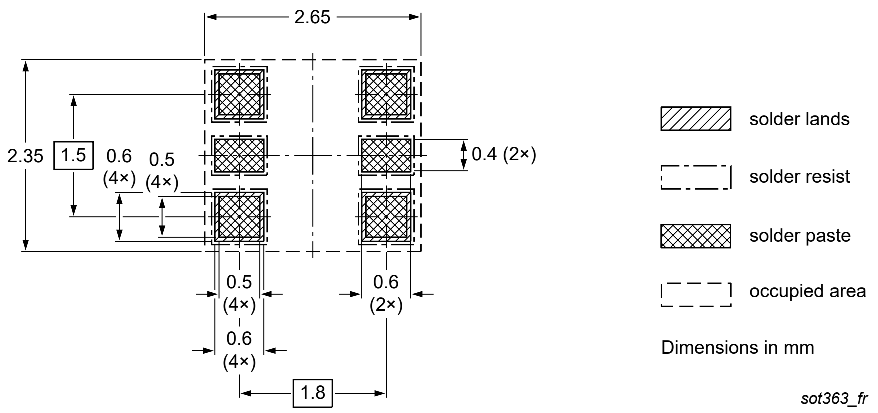


Fig. 24. Reflow soldering footprint for SOT363 (SC-88)

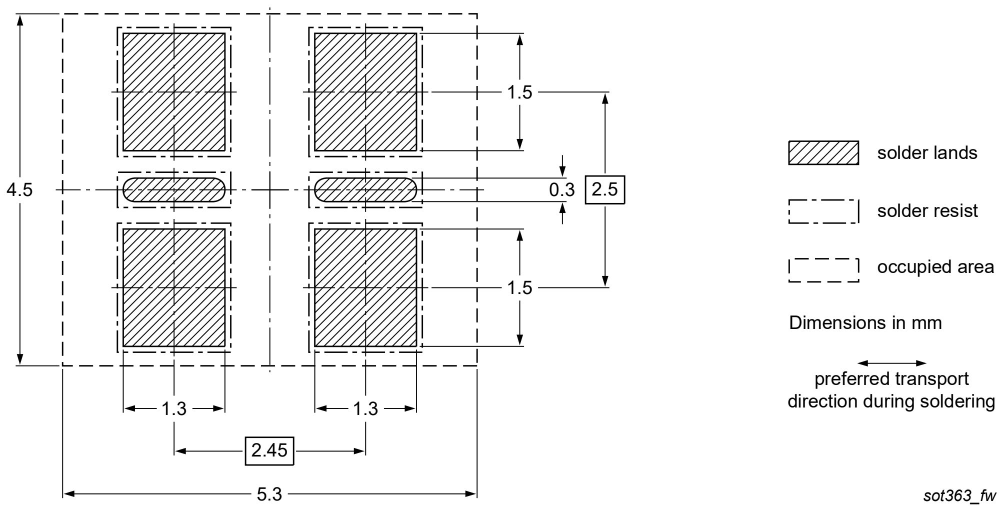


Fig. 25. Wave soldering footprint for SOT363 (SC-88)

14. Revision history

Table 10. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
NHUMB10_13_9_SER v.1	20200723	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.
[2] The term 'short data sheet' is explained in section "Definitions".
[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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